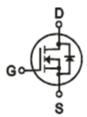


Features

- VDS (V)=600V
- ID=4.0A
- $R_{DS(ON)} \le 2.4 \Omega \text{ (VGS = 10V)}$









●最大额定值(Tc=25°C)

● Absolute Maximum Ratings (Tc=25°C)TO-220/220F/TO-252

参数 PARAMETER	符号 SYMBOL	額定值 VALUE	单位 UNIT
漏-源电压 Drain-source Voltage	V_{DS}	600	V
栅-源电压 gate-source Voltage	V_{GS}	± 30	V
漏极电流 Continuous Drain Current TC=25℃	lο	4.0	А
漏极电流 Continuous Drain Current TC=100℃	l _D	2.5	А
最大脉冲电流 Drain Current —Pulsed ①	I _{DM}	16	А
耗散功率 Power Dissipation	P _{tot}	TO-220:104 TO-220F36	W
最高结温 Junction Temperature	Tj	150	°C
存储温度 Storage Temperature	T _{STG}	-55-150	°C
单脉冲雪崩能量 Single Pulse Avalanche Energy②	Eas	128	mJ



N-沟道功率 MOS 管

●电特性 (Tc=25°C)

●Electronic Characteristics (Tc=25°C)

参数 PARAMETER	符号 SYMBOL TEST CONDITION		最小值 MIN	典型值 TYP	最大值 MAX	单位 UNIT
漏 - 源击穿电压 Drain-source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250μA	600			٧
击穿电压温度系数 Breakdown Voltage Temperature Coefficient	Δ BV _{DSS} / ΔΤj	I _D =250uA, Referenced to 25°C		0.6		V/°C
栅极开启电压 Gate Threshold Voltage	V _{GS(TH)}	V _{GS} =V _{DS,} I _D =250μA	2.0		4.0	٧
漏-源漏电流	l	V _{DS} =600V, V _{GS} =0V, Tj=25°C			25	μΑ
Drain-source Leakage Current	I _{DSS}	V _{DS} =480V, V _{GS} =0V, Tj=125°C			250	μΑ
跨导 Forward Transconductance	gfs	V _{DS} =40V, I _D =2.0A		2.5		S



N-沟道功率 MOS 管

参数 PARAMETER	符号 SYMBOL	灣试条件 TEST CONDITION	最小值 MIN	典型值 TYP	最大值 MAX	单位 UNIT
栅极漏电流 Gate-body Leakage Current (V _{DS} = 0)	lgss	V _{GS} =±30V			±100	nA
漏-源导通电阻 Static Drain-source On Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =2.0A ③		2.00	2.4	Ω
输入电容 Input Capacitance	Ciss	V_{GS} = 0V, V_{DS} = 25V F = 1.0MHZ		580		pF
关断延迟 Turn -Off Delay Time	Td(off)	V_{DD} =300V, I_D =4.0A R_G =25 Ω ③		20		ns
栅极电荷 Total Gate Charge	Qg	1 404 1/ 400/		14.8		nC
栅源电荷 Gate-to-Source Charge	Qgs	$I_D = 4.0A, V_{DS} = 480V$ $V_{GS} = 10V$ $\textcircled{3}$		3.4		nC
栅漏电荷 Gate-to-Drain Charge	Qgd	•		4.8		nC
二极管正向电流 Continuous Diode Forward Current	I s				4.0	Α
二极管正向压降 Diode Forward Voltage	V _{SD}	Tj=25°C, Is=4.0A V _{GS} =0V			1.4	>
反向恢复时间 Reverse Recovery Time	trr	Tj=25°C, If=4.0A		390		ns
反向恢复电荷 Reverse Recovery Charge	Qrr	di/dt=100A/µs ③		1.5		uC

●热特性

●Thermal Characteristics

多数	符号	最大值 MAX		单位	
PARAMETER	SYMBOL	TO-220	TO-220F		UNIT
热阻结 - 壳 Thermal Resistance Junction-case	Rth _{JC}	1.20	3.47		°C/W
热阻结 - 环境 Thermal Resistance Junction-ambient	Rth _{JA}	62.5	62.5		°C/W

注释(Notes):

① 脉冲宽度: 以最高结温为限制

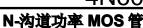
Repetitive rating: Pulse width limited by maximum junction temperature

② 初始结温=25°C, V_{DD} =50V, L=25mH, R_G =25 Ω , I_{AS} =4.0A

Starting Tj=25°C, V_{DD} =50V, L=25mH, R_G =25 Ω , I_{AS} =4.0A

③ 脉冲测试: 脉冲宽度≤300μs , 占空比≤2 %

Pulse Test : Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$





● 特性曲线

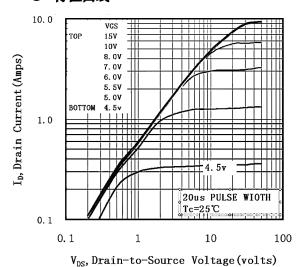


图 1 输出特性曲线, Tc=25℃ Fig1 Typical Output Characteristics, Tc=25℃

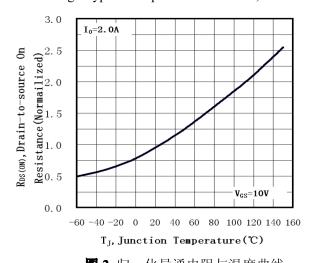
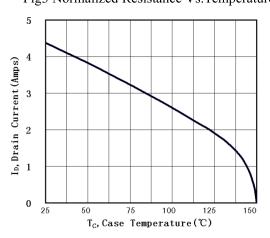


图 3 归一化导通电阻与温度曲线 Fig3 Normalized Resistance Vs.Temperature



■ 5 最大漏极电流与壳温曲线

Fig5 Maximum Drain Current Vs.Case Temperature

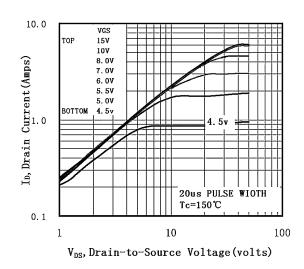


图 2 输出特性曲线, Tc=150℃ Fig2 Typical Output Characteristics, Tc=150℃

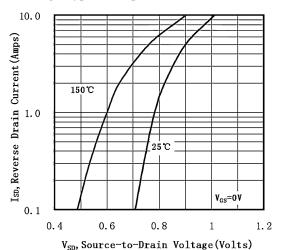


图 4 二极管正向电压曲线

Fig4 Typical Source-Drain Diode Forward Voltage



N-沟道功率 MOS 管

● 特性曲线

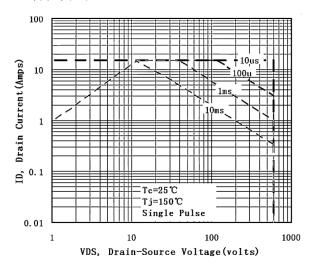


图 6-1 4N60 (TO-220)

最大安全工作区曲线

Fig6-1 Maximum Safe Operating Area

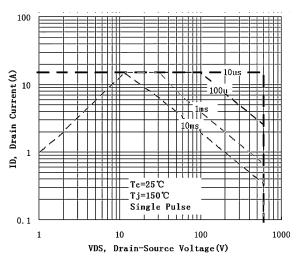


图6-3 4N60(TO-252)

最大安全工作区曲线

Fig6-3 Maximum Safe Operating Area

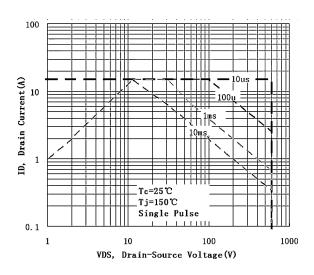


图 6-2 4N60(TO-220F)

最大安全工作区曲线

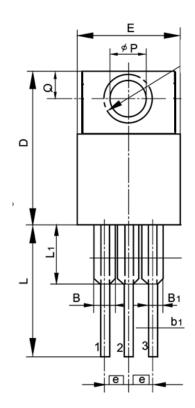
Fig6-2 Maximum Safe Operating Area

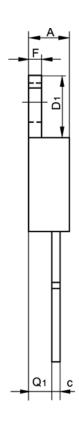


TO-220 **封装**

单位:毫米/UNIT: mm

符号 SYMBOL	最小值 min	典型值 nom	最大值 max	符号 SYMBOL	最小值 min	典型值 nom	最大值 max
Α	4.00		4.80	Е	9.90		10.70
В	1.20		1.50	е		2.54	
B1	1.00		1.40	F	1.10		1.45
b1	0.65		1.00	L	12.50		14.50
С	0.35		0.75	L1	3.00	3.50	4.00
D	15.00		16.50	Q	2.50		3.00
D1	5.90		6.90	Q1	2.00		3.00
				ΦР	3.60		3.90



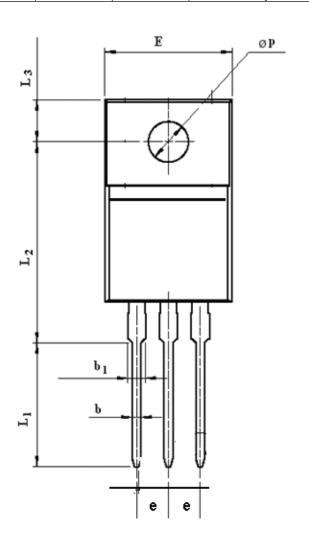


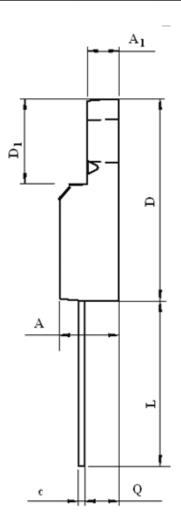


TO-220F 封装

单位:毫米/UNIT: mm

符号 SYMBOL	最小值 min	典型值 nom	最大值 max	符号 SYMBOL	最小值 min	典型值 nom	最大值 max
Α	4.40		4.95	е		2.54	
A ₁	2.30		2.90	L	12.50		14.30
b	0.45		0.90	L ₁	9.10		10.05
b ₁	1.10		1.70	L ₂	15.00		16.00
С	0.35		0.90	L ₃	3.00		4.00
D	14.50		17.00	øр	3.00		3.50
D1	6.10		9.00	Q	2.30		2.80
Е	9.60		10.30				



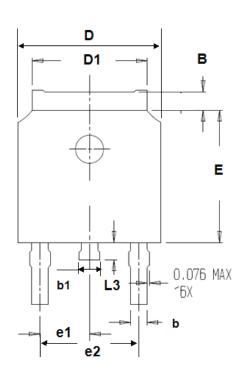


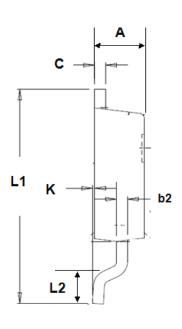


TO-252 封装机械尺寸 **TO-252 MECHANICAL DATA**

单位:毫米/UNIT: mm

				. —	•,
符号 SYMBOL	最小值 min	最大值 max	符号 SYMBOL	最小值 min	最大值 max
Α	2.10	2.50	В	0.85	1.25
b	0.50	0.80	b1	0.50	0.90
b2	0.45	0.70	С	0.45	0.70
D	6.30	6.75	D1	5.10	5.50
E	5.30	6.30	e1	2.25	2.35
L1	9.20	10.60	e2	4.45	4.75
L2	0.90	1.75	L3	0.60	1.10
K	0.00	0.23			







Ordering information

Order code	Package	Baseqty	Deliverymode
UMW 4N60L	TO-252	2500	Tape and reel
UMW 4N60	TO-220	1000	Tube and box
UMW 4N60L	TO-220F	1000	Tube and box